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FEATURES

- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication
- **Enhanced Diminishing Manufacturing** Sources (DMS) Support
- **Enhanced Product-Change Notification**
- Qualification Pedigree (1)
- **Member of the Texas Instruments** Widebus™ Family
- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Typical V_{OLP} (Output Ground Bounce) <1 V at $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$
- **High-Impedance State During Power Up and Power Down**
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (-32-mA I_{OH}, 64-mA I_{OL})
- Latch-Up Performance Exceeds 500 mA Per JESD 70
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883. Method 3015: Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Shrink Small-Outline (DL) Package
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

(TOP VIEW)									
1DIR [1B1 [1B2 [GND [1B3 [1B4 [1 2 3 4 5	48 47 46 45 44	1 OE 1A1 1A2 GND 1A3 1A4						
V _{CC}			V _{CC}						
1B5 L			1A5						
1B6 [1A6						
GND [GND						
1B7			1A7						
1B8 [1A8						
2B1			2A1						
2B2			2A2						
GND [GND						
2B3			2A3						
2B4		32	2A4						
v _{cc} [18	31] v _{cc}						
2B5 🛚	19		2A5						
2B6 [20	29	2A6						
GND [21	28	GND						
2B7	22	27	2A7						
2B8	23	26	2A8						
2DIR	24	25	2 <u>OE</u>						

DL PACKAGE

(TOD VIEW)

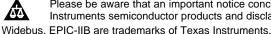
DESCRIPTION/ORDERING INFORMATION

The SN74ABT16245A-EP is a 16-bit noninverting 3-state transceiver designed for synchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

This device can be used as two 8-bit transceivers or one 16-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so that the buses are effectively isolated.

When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impendance state above 2.1 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ABT16245A-EP is characterized for operation from -55°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

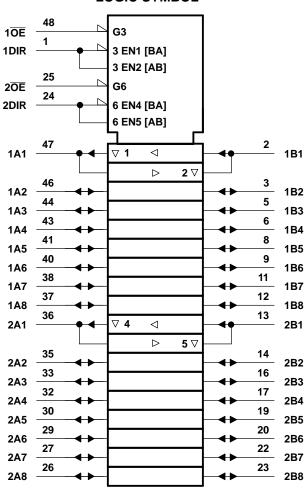
T _A	PACKAC	GE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
-55°C to 125°C	SSOP - DL	Reel of 1000	CABT16245AMDLREP	ABT16245AMEP		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (EACH 8-BIT SECTION)

INP	UTS	OPERATION				
ŌĒ	DIR	OFERATION				
L	L	B data to A bus				
L	Н	A data to B bus				
Н	Χ	Isolation				

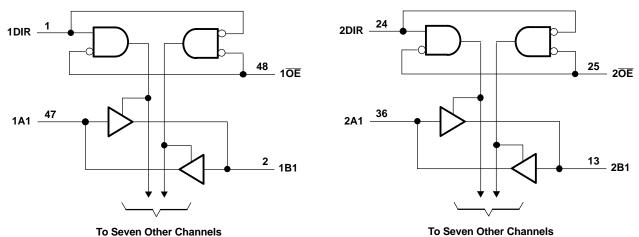
LOGIC SYMBOL(1)



(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range (except I/O ports) ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high or	power-off state	-0.5	5.5	V
Io	Current into any output in the low state			96	mA
I _{IK}	Input clamp current	V _I < 0		-18	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
θ_{JA}	Package thermal impedance ⁽³⁾			94	°C/W
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		4.5	5.5	V
V _{IH}	High-level input voltage		2		V
V _{IL}	Low-level input voltage			0.8	V
VI	Input voltage	0	V _{CC}	V	
I _{OH}	High-level output current			-24	mA
I _{OL}	Low-level output current			48	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		μs/V
T _A	Operating free-air temperature		-55	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51.

SN74ABT16245A-EP 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS





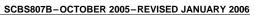
Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

				1	Γ _A = 25°C					
PAR	AMETER	TEST CON	DITIONS		TYP ⁽¹⁾	MAX	MIN	MAX	UNIT	
V _{IK}		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2		-1.2	V	
		$V_{CC} = 4.5 \text{ V},$ $I_{OH} = -3 \text{ mA}$ 2.5					2.5			
.,		$V_{CC} = 5 V$,	$I_{OH} = -3 \text{ mA}$	3			3		V	
V_{OH}		V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2		V	
		V _{CC} = 4.5 V	$I_{OH} = -32 \text{ mA}$	2						
V	V _{CC} = 4.5 V		I _{OL} = 48 mA			0.55		0.55	V	
V_{OL}		V _{CC} = 4.5 V	I _{OL} = 64 mA			0.55			V	
V_{hys}					100				mV	
	Control inputs	$V_{CC} = 0$ to 5.5 V, $V_{I} = V_{CC}$ or C	GND			±1		±1	^	
l _l	A or B port	V _{CC} = 2.1 V to 5.5 V, V _I = V _{CC}	or GND			±20		±100	μА	
I _{OZPU}	1	$V_{CC} = 0$ to 2.1 V, $V_{O} = 0.5$ V to	2.7 V, OE = X			±50			μΑ	
I _{OZPD}		$V_{CC} = 2.1 \text{ V to } 0, V_{O} = 0.5 \text{ V to}$	$2.7 \text{ V}, \overline{\text{OE}} = X$ ± 50			±50			μΑ	
I _{OZH} ⁽²⁾	$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}, V_{O} = 2.7 \text{ V}$		$V, \overline{OE} \ge 2 V$			10 ⁽³⁾		10	μΑ	
I _{OZL} ⁽²⁾		$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}, V_{O} = 0.5$	V, OE ≥ 2 V		-10 ⁽³⁾		-10	μΑ		
I _{off}		$V_{CC} = 0$,	V_I or $V_O \le 5.5 \text{ V}$			±100			μΑ	
I _{CEX}		$V_{CC} = 5.5 \text{ V}, V_{O} = 5.5 \text{ V}$	Outputs high			50		50	μΑ	
I _O ⁽⁴⁾		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	-50	-180	mA	
		.,	Outputs high			2		2		
I_{CC}	A or B port	$V_{CC} = 5.5 \text{ V}, I_{O} = 0,$ $V_{I} = V_{CC} \text{ or GND}$	Outputs low			32		32	mA	
	Port	17 100 01 0110	Outputs disabled		2			2		
	Data	$V_{CC} = 5.5 \text{ V},$	Outputs enabled			2		1.5		
$\Delta I_{CC}^{(5)}$	inputs	One input at 3.4 V, Other inputs at V _{CC} or GND	Outputs disabled			0.05		1	mA	
	Control inputs $V_{CC} = 5.5 \text{ V}$, One input at 3.4 Other inputs at V_{CC} or GND		V,			1.5		1.5		
Ci	Control inputs	V _I = 2.5 V or 0.5 V			3				pF	
C _o	A or B port	V _O = 2.5 V or 0.5 V			6				pF	

 ⁽¹⁾ All typical values are at V_{CC} = 5 V.
 (2) The parameters I_{OZH} and I_{OZL} include the input leakage current.
 (3) This limit may vary among suppliers.

 ⁽⁴⁾ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
 (5) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.





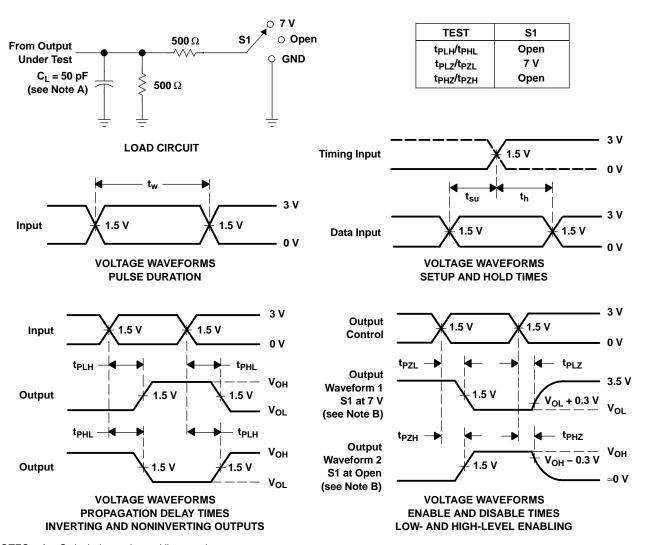
Switching Characteristics

over recommended operating ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	_{CC} = 5 V, \(= 25°C	,	MIN	MAX	UNIT
	(INFOT)	(001701)	MIN	TYP	MAX			
t _{PLH}	A or B	A or B B or A		2.2	3.4	0.5	4	20
t _{PHL}	AUID	BUIA	0.5	2.3	3.8	0.5	4.6	ns
t _{PZH}	 OE	B or A	0.8	3.6	5.2	0.8	5.5	20
t _{PZL}	OE .	D OI A	0.9	3.7	6.1	0.1	7.3	ns
t _{PHZ}	OE	B or A	1.3	4.4	5.8	1.3	6.3	20
t _{PLZ}	OE .	BUIA	1.4	3.3	4.7	1.4	5.5	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

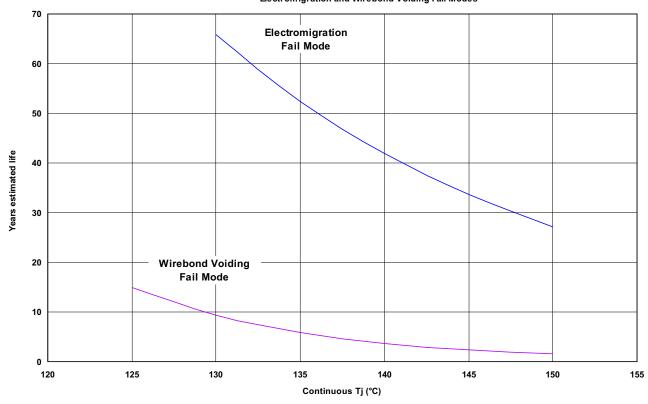
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2.5$ ns. $t_f \leq 2.5$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

SN74ABT16245A-EP



CABT16245A*DL*EP Estimated Device Life at Elevated Temperatures Electromigration and Wirebond Voiding Fail Modes





PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CABT16245AMDLREP	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ABT16245AMEP	Samples
V62/06609-01XE	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ABT16245AMEP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF SN74ABT16245A-EP:

● Catalog: SN74ABT16245A

• Military: SN54ABT16245A

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

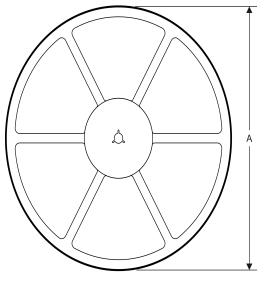
• Military - QML certified for Military and Defense Applications

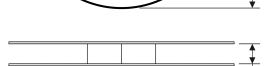
PACKAGE MATERIALS INFORMATION

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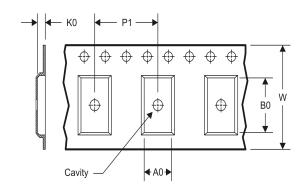
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CABT16245AMDLREP	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

www.ti.com 14-Jul-2012

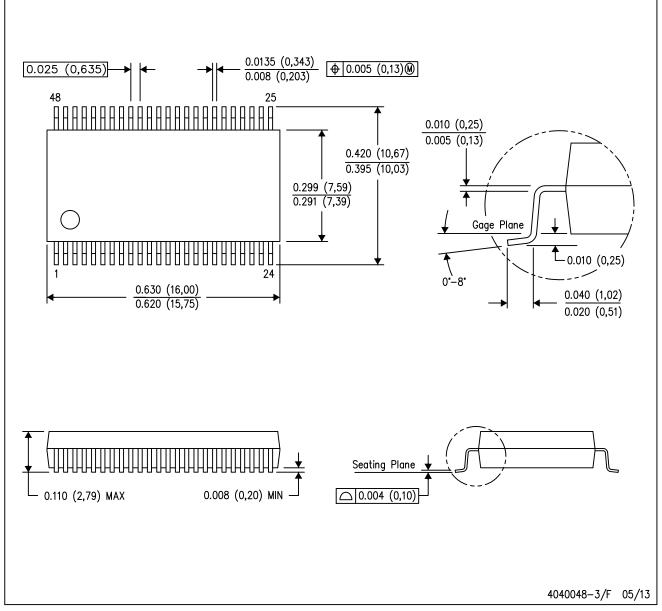


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CABT16245AMDLREP	SSOP	DL	48	1000	367.0	367.0	55.0

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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